

**Trans IGBT Chip N-CH 1700V 38A 200mW 3-Pin(3+Tab)
ISOPLUS 247**



Images are for reference only

[Inquiry](#)

Manufacturer: [Littelfuse Inc](#)

Package/Case: ISOPLUS247

Product Type: Thyristors

Lifecycle: Obsolete

General Description

BiMOSFETs are devices, which have combined strengths of MOSFETs and IGBTs. Non-epitaxial construction and new fabrication processes were used in making BiMOSFETs a great success. These high voltage devices are ideal for parallel operation due to the positive voltage temperature coefficient of both of its saturation voltage, and the forward voltage drop of its intrinsic diode. Furthermore, this “free” intrinsic body diode serves as a protection diode, providing an alternative path for the inductive load current during device turn-off, preventing high Ldi/dt voltage transients from inflicting damage to the device.

Key Features

- Electrically isolated tab
- High current handling capability
- MOS gate turn-ON - drive simplicity
- Rugged NPT structure
- UL94V-0 Flammability rating

Application

- Radar transmitter power supplies
- Radar pulse modulators
- Capacitor discharge circuits
- High voltage power supplies
- AC switches
- HV circuit breakers
- Pulser circuits
- High voltage test equipment
- Laser & X-ray generators

Recommended For You

IXGH48N60C3D1

Littelfuse Inc

TO-247

IXYX100N120C3

Littelfuse Inc

PLUS247

IXGH30N60B2D1

Littelfuse Inc

TO-247

IXYN30N170CV1

Littelfuse Inc

N

IXBH16N170

Littelfuse Inc

TO-247

IXGH60N60C2

Littelfuse Inc

TO-247

IXGH48N60A3

Littelfuse Inc

TO-247

IXGN320N60A3

Littelfuse Inc

MODULE

IXGH60N60C3

Littelfuse Inc

TO-247

IXGP20N120A3

Littelfuse Inc

TO-220

IXYR50N120C3D1

Littelfuse Inc

ISOPLUS247

IXYH50N65C3D1

Littelfuse Inc

TO-247

IXGP8N100

Littelfuse Inc

TO-220

IXTQ460P2

Littelfuse Inc

TO-3P

IXGR48N60C3D1

Littelfuse Inc

TO-247